## NSN 5961-01-286-6640

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.260 inches

#### Terminal Length:

0.500 inches

#### **Overall Diameter:**

0.370 inches

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-39

Electrode Internally-electrically Connected To Case:

#### Collector

**Mounting Method:** 

Terminal

### Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

500.0 collector to base voltage, dc and 450.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, dc

#### **Current Rating Per Characteristic:**

1.00 amperes source cutoff current and 0.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### Test Data Document:

08748-29050 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

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